CMOS Digital Integrated Circuits Silicon Monolithic

TC7WZ00FK

1. Functional Description

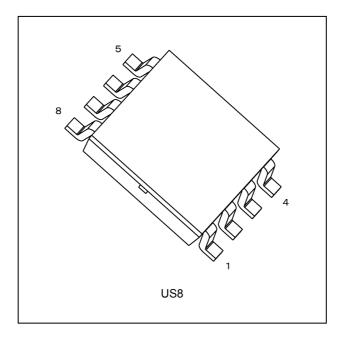
• Dual 2-Input NAND Gate

2. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 2)
- (3) High output current: ± 24 mA (min) (V_{CC} = 3.0 V)
- (4) Super high speed operation: $t_{pd} = 2.4$ ns (typ.) (V_{CC} = 5.0 V, C_L = 50 pF)
- (5) Operation voltage range: V_{CC} = 1.65 to 5.5 V
- (6) 5.5 V tolerant inputs
- (7) 5.5 V power down protection output
- (8) Matches the performance of TC74LCX series when operated at $3.3 \text{ V} V_{CC}$
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

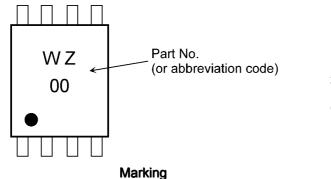
Note 2: For devices with the ordering part number ending in J(CT. T_{opr} = -40 to 85 °C for the other devices.

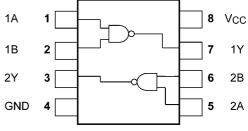
3. Packaging



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4. Marking and Pin Assignment







5. IEC Logic Symbol



6. Truth Table

| А | В | Y |
|---|---|---|
| L | L | Н |
| L | Н | Н |
| Н | L | Н |
| Н | Н | L |

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics | Symbol | Note | Rating | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage | V _{CC} | | -0.5 to 6.0 | V |
| Input voltage | V _{IN} | | -0.5 to 6.0 | V |
| DC output voltage | V _{OUT} | (Note 1) | -0.5 to 6.0 | V |
| | | (Note 2) | -0.5 to V _{CC} + 0.5 | |
| Input diode current | I _{IK} | | -20 | mA |
| Output diode current | Ι _{ΟΚ} | (Note 3) | -20 | mA |
| DC output current | I _{OUT} | | ±50 | mA |
| V _{CC} /ground current | I _{CC} | | ±50 | mA |
| Power dissipation | PD | | 200 | mW |
| Storage temperature | T _{stg} | | -65 to 150 | °C |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{CC} = 0 V

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND

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8. Operating Ranges (Note)

| Characteristics | Symbol | Note | Test Condition | Rating | Unit |
|--------------------------|------------------|----------|----------------------------------------------|----------------------|------|
| Supply voltage | V _{CC} | | — | 1.65 to 5.5 | V |
| | | (Note 1) | _ | 1.5 to 5.5 | |
| Input voltage | V _{IN} | | _ | 0 to 5.5 | V |
| Output voltage | V _{OUT} | (Note 2) | — | 0 to 5.5 | V |
| | | (Note 3) | _ | 0 to V _{CC} | |
| Operating temperature | T _{opr} | (Note 4) | — | -40 to 125 | °C |
| | | (Note 5) | _ | -40 to 85 | |
| Input rise and fall time | dt/dv | | V_{CC} = 1.8 \pm 0.15 V, 2.5 \pm 0.2 V | 0 to 20 | ns/V |
| | | | V_{CC} = 3.3 ± 0.3 V | 0 to 10 | |
| | | | V_{CC} = 5.0 ± 0.5 V | 0 to 5 | |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Data retention only

Note 2: V_{CC} = 0 V

Note 3: High (H) or Low (L) state.

Note 4: For devices with the ordering part number ending in J(CT.

Note 5: For devices except those with the ordering part number ending in J(CT.

9. Electrical Characteristics

9.1. DC Characteristics (Unless otherwise specified, Ta = 25 °C)

| Characteristics | Symbol | Test Condition | I | V _{CC} (V) | Min | Тур. | Max | Unit |
|------------------------------|------------------|---------------------------------------------|---------------------------|---------------------|----------------------|------|----------------------|------|
| High-level input voltage | V _{IH} | _ | | 1.65 to 1.95 | $V_{CC} \times 0.75$ | _ | | V |
| | | | | 2.3 to 5.5 | $V_{CC} 	imes 0.70$ | | _ | 1 |
| Low-level input voltage | VIL | — | | 1.65 to 1.95 | _ | _ | $V_{CC} \times 0.25$ | V |
| | | | | 2.3 to 5.5 | _ | _ | $V_{CC} \times 0.30$ |] |
| High-level output voltage | V _{OH} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OH} = -100 μA | 1.65 | 1.55 | 1.65 | — | V |
| | | | | 2.3 | 2.2 | 2.3 | — |] |
| | | | | 3.0 | 2.9 | 3.0 | — |] |
| | | | | 4.5 | 4.4 | 4.5 | — | |
| | | | I _{OH} = -4 mA | 1.65 | 1.29 | 1.52 | — |] |
| | | | I _{OH} = -8 mA | 2.3 | 1.9 | 2.15 | _ |] |
| | | | I _{OH} = -16 mA | 3.0 | 2.4 | 2.8 | — | |
| | | | I _{OH} = -24 mA | 3.0 | 2.3 | 2.68 | — |] |
| | | | I _{OH} = -32 mA | 4.5 | 3.8 | 4.2 | _ |] |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} | I _{OL} = 100 μA | 1.65 | _ | 0.0 | 0.1 | V |
| | | | | 2.3 | _ | 0.0 | 0.1 |] |
| | | | | 3.0 | _ | 0.0 | 0.1 | |
| | | | | 4.5 | _ | 0.0 | 0.1 | |
| | | | I _{OL} = 4 mA | 1.65 | _ | 0.08 | 0.24 |] |
| | | | I _{OL} = 8 mA | 2.3 | _ | 0.1 | 0.3 |] |
| | | | I _{OL} = 16 mA | 3.0 | _ | 0.15 | 0.4 | |
| | | | I _{OL} = 24 mA | 3.0 | _ | 0.22 | 0.55 |] |
| | | | I _{OL} = 32 mA | 4.5 | _ | 0.22 | 0.55 |] |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | _ | ±1.0 | μA |
| Power-OFF leakage current | I _{OFF} | V _{IN} or V _{OUT} = 5.5 V | | 0 | _ | | 1 | μA |
| Quiescent supply current | I _{CC} | V _{IN} = 5.5 V or GND | | 1.65 to 5.5 | _ | _ | 1 | μA |

9.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

| Characteristics | Symbol | Test Condition | on | V _{CC} (V) | Min | Max | Unit |
|---------------------------|------------------|--------------------------------------|---------------------------|---------------------|---------------------|----------------------|------|
| High-level input voltage | VIH | _ | | 1.65 to 1.95 | $V_{CC} 	imes 0.75$ | _ | V |
| | | | | 2.3 to 5.5 | $V_{CC} 	imes 0.70$ | _ | |
| Low-level input voltage | VIL | _ | | 1.65 to 1.95 | — | $V_{CC} 	imes 0.25$ | V |
| | | | | 2.3 to 5.5 | _ | $V_{CC} \times 0.30$ | |
| High-level output voltage | V _{OH} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OH} = -100 μA | 1.65 | 1.55 | _ | V |
| | | | | 2.3 | 2.2 | _ | |
| | | | | 3.0 | 2.9 | — | |
| | | | | 4.5 | 4.4 | _ | |
| | | | I _{OH} = -4 mA | 1.65 | 1.29 | _ | |
| | | | I _{OH} = -8 mA | 2.3 | 1.9 | _ | |
| | | | I _{OH} = -16 mA | 3.0 | 2.4 | _ | |
| | | | I _{OH} = -24 mA | 3.0 | 2.3 | _ | |
| | | | I _{OH} = -32 mA | 4.5 | 3.8 | — | |
| Low-level output voltage | V _{OL} | $V_{IN} = V_{IH}$ | I _{OL} = 100 μA | 1.65 | — | 0.1 | V |
| | | | | 2.3 | _ | 0.1 | |
| | | | | 3.0 | _ | 0.1 | |
| | | | | 4.5 | — | 0.1 | |
| | | | I _{OL} = 4 mA | 1.65 | — | 0.24 | |
| | | | I _{OL} = 8 mA | 2.3 | _ | 0.3 | |
| | | | I _{OL} = 16 mA | 3.0 | — | 0.4 | |
| | | | I _{OL} = 24 mA | 3.0 | — | 0.55 | |
| | | | I _{OL} = 32 mA | 4.5 | — | 0.55 | |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | ±10.0 | μA |
| Power-OFF leakage current | I _{OFF} | V_{IN} or V_{OUT} = 5.5 V | | 0 | _ | 10 | μA |
| Quiescent supply current | I _{CC} | V _{IN} = 5.5 V or GND | | 1.65 to 5.5 | _ | 10 | μA |

9.3. DC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C)

| Characteristics | Symbol | Test Condition | | V _{CC} (V) | Min | Max | Unit |
|---------------------------|------------------|---------------------------------------------|---------------------------|---------------------|---------------------|---------------------|------|
| High-level input voltage | VIH | — | | 1.65 to 1.95 | $V_{CC} 	imes 0.75$ | — | V |
| | | | | 2.3 to 5.5 | $V_{CC} 	imes 0.70$ | — | |
| Low-level input voltage | VIL | _ | | 1.65 to 1.95 | — | $V_{CC} 	imes 0.25$ | V |
| | | | | 2.3 to 5.5 | _ | $V_{CC} 	imes 0.30$ | |
| High-level output voltage | V _{OH} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OH} = -100 μA | 1.65 | 1.55 | _ | V |
| | | | | 2.3 | 2.2 | _ | |
| | | | | 3.0 | 2.9 | — | |
| | | | | 4.5 | 4.4 | — | |
| | | | I _{OH} = -4 mA | 1.65 | 0.95 | — | |
| | | | I _{OH} = -8 mA | 2.3 | 1.7 | — | |
| | | | I _{OH} = -16 mA | 3.0 | 2.2 | _ | |
| | | | I _{OH} = -24 mA | 3.0 | 2.0 | _ | |
| | | | I _{OH} = -32 mA | 4.5 | 3.4 | _ | |
| Low-level output voltage | V _{OL} | $V_{IN} = V_{IH}$ | I _{OL} = 100 μA | 1.65 | _ | 0.1 | V |
| | | | | 2.3 | _ | 0.1 | |
| | | | | 3.0 | _ | 0.1 | |
| | | | | 4.5 | _ | 0.1 | |
| | | | I _{OL} = 4 mA | 1.65 | _ | 0.7 | |
| | | | I _{OL} = 8 mA | 2.3 | _ | 0.45 | |
| | | | I _{OL} = 16 mA | 3.0 | — | 0.6 | |
| | | | I _{OL} = 24 mA | 3.0 | — | 0.8 | |
| | | | I _{OL} = 32 mA | 4.5 | — | 0.8 | |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | ±20.0 | μA |
| Power-OFF leakage current | I _{OFF} | V _{IN} or V _{OUT} = 5.5 V | | 0 | — | 100 | μA |
| Quiescent supply current | I _{CC} | V _{IN} = 5.5 V or GND | | 1.65 to 5.5 | — | 100 | μA |

Note: For devices with the ordering part number ending in J(CT.

9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | C _L (pF) | Min | Тур. | Max | Unit |
|------------------------|------------------------------------|----------|------------------------|----------------------------------|---------------------|-----|------|-----|------|
| Propagation delay time | t _{PLH} ,t _{PHL} | | $R_L = 1 M\Omega$ | $\textbf{1.8} \pm \textbf{0.15}$ | 15 | 2.0 | 5.3 | 9.6 | ns |
| | | | | $\textbf{2.5}\pm\textbf{0.2}$ | | 1.2 | 3.2 | 5.3 | |
| | | | | $\textbf{3.3}\pm\textbf{0.3}$ | | 0.8 | 2.4 | 3.7 | |
| | | | | 5.0 ± 0.5 | | 0.5 | 1.9 | 2.9 | |
| | | | R _L = 500 Ω | $\textbf{3.3}\pm\textbf{0.3}$ | 50 | 1.2 | 3.0 | 4.6 | ns |
| | | | | 5.0 ± 0.5 | | 0.8 | 2.4 | 3.6 | |
| Input capacitance | C _{IN} | | _ | 0 to 5.5 | _ | _ | 3.0 | _ | pF |
| Power dissipation | C _{PD} | (Note 1) | — | 3.3 | _ | _ | 22 | _ | pF |
| capacitance | | | | 5.5 | | _ | 32 | _ | |

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per 1 gate)}$

9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | C _L (pF) | Min | Max | Unit |
|------------------------|------------------------------------|------------------------|----------------------------------|---------------------|-----|-----|------|
| Propagation delay time | t _{PLH} ,t _{PHL} | $R_L = 1 M\Omega$ | $\textbf{1.8} \pm \textbf{0.15}$ | 15 | 2.0 | 9.8 | ns |
| | | | 2.5 ± 0.2 | | 1.2 | 5.7 | |
| | | | 3.3 ± 0.3 | | 0.8 | 4.0 | |
| | | | 5.0 ± 0.5 | | 0.5 | 3.2 | |
| | | R _L = 500 Ω | $\textbf{3.3}\pm\textbf{0.3}$ | 50 | 1.2 | 4.9 | ns |
| | | | 5.0 ± 0.5 | | 0.8 | 3.9 | |

9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | C _L (pF) | Min | Max | Unit |
|------------------------|------------------------------------|------------------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | t _{PLH} ,t _{PHL} | R _L = 1 ΜΩ | 1.8 ± 0.15 | 15 | 2.0 | 11.0 | ns |
| | | | 2.5 ± 0.2 | | 1.2 | 8.0 | |
| | | | 3.3 ± 0.3 | | 0.8 | 5.5 | |
| | | | 5.0 ± 0.5 | | 0.5 | 5.0 | |
| | | R _L = 500 Ω | 3.3 ± 0.3 | 50 | 1.2 | 6.0 | ns |
| | | | 5.0 ± 0.5 | | 0.8 | 5.0 | |

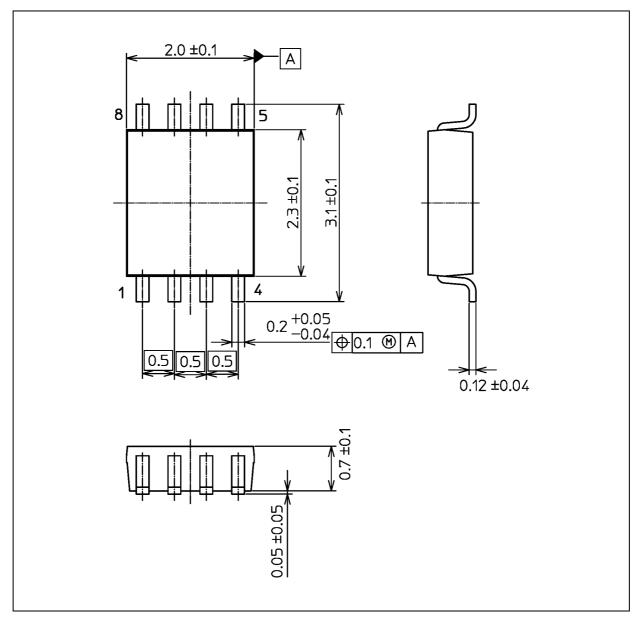
Note: For devices with the ordering part number ending in J(CT.



Package Dimensions

TC7WZ00FK

Unit: mm



Weight: 0.01 g (typ.)

| Package Name(s) |
|-----------------|
| JEDEC: SOT-765 |
| Nickname: US8 |

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